WHAT IS CLAIMED IS:

1	1. A substrate processing chamber comprising:
2	a chamber body;
3	a chamber top disposed on the chamber body; and
4	a transformer-coupled plasma generator plate within the substrate
5	processing chamber having a plurality of transformer cores within the transformer-
6	coupled plasma generator plate and a plurality of through holes forming conduits from
7	a first side of the transformer-coupled plasma generator plate to a second side of the
8	transformer-coupled plasma generator plate, a first conduit passing through a first
9	transformer core.
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1	2. The substrate processing chamber of claim 1 further comprising
2	a second conduit not passing through a transformer core.
,	3. The substrate processing chamber of claim 1 wherein the plasma
1	generator plate is flat.
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1	4. The substrate processing chamber of claim 1 further comprising
2	a second transformer core within the transformer-coupled plasma generating plate, a
3	first primary coil being disposed to electro-magnetically couple to the first transformer
4	core and a second primary coil being disposed to electro-magnetically couple to the
5	second transformer core, wherein the first primary coil and the second primary coil are
6	connected to each other in series.
1	5. The substrate processing chamber of claim 1 wherein the toroidal
2	transformer core comprises ferrite material.
1	6. The substrate processing chamber of claim 1 wherein the
2	transformer-coupled plasma generator plate includes a dielectric spacer between the
3	first side and the second side, and a remainder of an outer surface of the generator plate
4	comprises an electrical conductor.
1	7. The substrate processing chamber of claim 6 wherein the
2	dielectric spacer is disposed within a conduit through the transformer-coupled generato
3	plate.

1	6. The substrate processing chamber of claim 1 rather comprising
2	an alternating-current power supply configured to operate at a frequency of about
3	1 KHz-2 MHz.
1	9. A substrate processing chamber comprising:
2	a chamber body;
3	a chamber top disposed on the chamber body;
4	an alternating-current power supply; and
5	a transformer-coupled plasma generator plate having a plurality of
6	through holes forming conduits from a first side of the transformer-coupled plasma
7	generator plate within the substrate processing chamber to a second side of the
8	transformer-coupled plasma generator plate within the substrate processing chamber, a
9	first portion of the conduits passing through centers of a plurality of toroidal
10	transformer cores within the generator plate and a second portion of the conduits not
11	passing through centers of transformer cores, the generator having a first surface
12	comprising metal, a second surface comprising metal, and a plurality of dielectric
13	spacers disposed between the first surface and the second surface in each of the first
14	portion of the conduits.
1	10. A plasma generator plate comprising:
2	a first side;
3	a second side;
4	a first conduit passing from the first side to the second side through a
5	first transformer core within the plasma generator plate;
6	a second conduit passing from the first side to the second side through a
7	second transformer core.
1	11. The plasma generator plate of claim 10 further comprising a first
2	dielectric spacer in a first secondary current path around the first transformer core.
1	12. A method of processing a substrate in a plasma processing
2	system, the method comprising:
3	providing a substrate to a substrate holder in a processing chamber of the
4	plasma processing system;

5		flowing a plasma precursor into a multi-core transformer-coupled
6	plasma genera	tor;
7		generating a plasma from the plasma precursor with the multi-core
8	transformer co	upled plasma generator; and
9		processing the substrate.
1		13. The method of claim 12 wherein the multi-core transformer-
2	coupled plasm	a generator is within the processing chamber.
	٠	14. The method of claim 13 wherein the multi-core transformer-
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2		a generator is a generator plate comprising a plurality of transformer
3	•	ne generator plate and a plurality of through-holes forming conduits from
4	a first side of	the generator plate to a second side of the generator plate.
1		15. The method of claim 12 wherein plasma formed by the multi-
2.	core transform	ner-coupled plasma generator is coupled to the processing chamber
3	through a con	duit.
	•	16. The method of claim 15 wherein the multi-core transformer-
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2		na generator has a first conduit passing through a first transformer core
.3	and through a	second transformer core.
1		17. The method of claim 15 wherein the multi-core transformer-
2	coupled plasm	na generator has a first conduit passing through a first transformer core
3	and a second	conduit passing through a second transformer core.
		10 A 1 and a system comprising:
1		18. A plasma processing system comprising:
2		a first substrate support structure configured to hold a first substrate in a
3	processing ch	
4		a second substrate support structure configured to hold a second
5	substrate in t	ne processing chamber; and
6		a transformer-coupled plasma generator within the processing chamber
7	disposed bety	ween the first substrate support structure and the second substrate support
8	structure.	

1	19. The plasma processing system of claim 18 wherein the
2	transformer-coupled plasma generator includes a toroidal transformer core.
1	20. The plasma processing system of claim 18 wherein the plasma
2	generator comprises a plasma generating plate having a plurality of transformer cores
3	within the plasma generating plate and a plurality of through holes forming conduits
4	from a first side of the plate to a second side of the plate.
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1	21. A method of simultaneously processing substrates in a plasma
2	processing system, the method comprising:
3	providing a first wafer and a second wafer to a processing chamber;
4	flowing plasma precursor into the chamber;
5	generating a plasma with a transformer-coupled plasma generator
6	disposed between the first wafer and the second wafer; and
7	simultaneously processing the first wafer and the second wafer.
1	22. A plasma generator comprising:
2	an inlet in fluid communication with;
3	a first conduit passing through
4	a first toroidal transformer core and through
5	a second toroidal transformer core;
6	a second conduit completing a plasma current circuit, in cooperation
7	with the first conduit, around the first toroidal transformer core and around the second
8	toroidal transformer core; and
9	an outlet in fluid communication with the first conduit.
1	23. A plasma generator comprising:
2	an inlet in fluid communication with
3	a first conduit passing through a first transformer core and with
4	a second conduit passing through a second transformer core;
5	a third conduit in fluid communication with the first conduit to complete
6	a first plasma current circuit around the first transformer and in fluid communication
7	with the second conduit to complete a second plasma current circuit around the second
8	transformer; and

9	an outlet in fluid communication with at least the first conduit and the
10	second conduit.
1	24. A substrate processing system comprising:
2	a process chamber with a chamber inlet;
3	a chamber exhaust; and
4	a transformer-coupled plasma generator having a first core,
5	a first conduit passing through the first core,
6	a second core,
7	a second conduit passing through the second core, and
8	a third conduit in fluid communication with the first conduit and
9	the second conduit to complete a plasma current circuit path through the process
10	chamber.
1	25. The substrate processing system of claim 24 wherein the third
2	conduit is a center conduit completing a first plasma current circuit path around the first
3	core through the process chamber and the first conduit and completing a second plasma
4	current circuit path around the second core through the process chamber and the second
5	conduit.
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1	26. The substrate processing system of claim 24 wherein the first
2	conduit and the second conduit comprise metal and further comprising a dielectric
3	spacer in the plasma current circuit path.
1	27. The substrate processing system of claim 24 further comprising:
2	a fourth conduit passing through
3	a third core; and
4	a fifth conduit passing through
5	a fourth core.
1	28. The substrate processing system of claim 24 further comprising:
2	a first primary coil disposed to couple electro-magnetic energy to the
3	first core;
4	a second primary coil disposed to couple electro-magnetic energy to the
5	second core;
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6	a third primary coil disposed to couple electro-magnetic energy to the
7	third core;
8	a fourth primary coil disposed to couple electro-magnetic energy to the
9	fourth core, wherein the first primary coil, the second primary coil, the third primary
10	coil, and the forth primary coil are coupled to an AC power supply.
1	29. The substrate processing system of claim 28 wherein the first
2	primary coil, the second primary coil, the third primary coil, and the fourth primary coil
3	are connected in series with the AC power supply.
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1	30. The substrate processing system of claim 28 wherein the first
2	primary coil, the second primary coil, the third primary coil, and the fourth primary coil
3	are connected in parallel to the AC power supply.
1	31. A plasma generator comprising:
2	an inlet configured to receive a plasma precursor, the inlet in fluid
3	communication with a first plasma current path and with a second plasma current path;
4	a first conduit passing through
5	a first transformer core;
6	a second conduit passing through
7	a second transformer core, wherein the first conduit is essentially co-
8	linear with the second conduit.
1	32. A plasma generator comprising:
2	an outer shell surrounding a first inner shell housing a first toroidal
3	transformer core; and
4	a second inner shell housing a second toroidal transformer core, wherein
5	the first toroidal transformer core and the second toroidal transformer core are disposed
6	along a common center axis.
1	33. The plasma generator of claim 32 wherein the first inner shell is
2	supported within the outer shell by a web allowing circulation of secondary plasma
3	current around the first inner shell within the outer shell.
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1	34. The plasma generator of claim 33 wherein the web contains an
2	electrical lead connected to a primary coil disposed to couple electro-magnetic energy
3	to the first toroidal transformer core.
1	35. The plasma generator of claim 32 wherein the first inner shell
2	includes a shaped bottom portion to provide a circular cross-section to the inner shell.
1	36. The plasma generator of claim 32 further comprising:
2	an inlet; and
3	an outlet, both the inlet and the outlet lying along the common center
4	axis.
1	37. An ion implantation system comprising:
2	an ion source having a toroidal plasma generator, and
3	an ion source aperture aligned essentially along a center line of the
4	toroidal plasma generator.
1	38. The ion implantation system of claim 37 further comprising a
2	first extraction electrode disposed to accelerate ions from the ion source toward a
3	second extraction electrode.
	27 wherein the toroidal
1	39. The ion implantation system of claim 37 wherein the toroidal
2	plasma generator includes a first core and a second core, the first core and the second
3	core being aligned essentially along a center line of the toroidal plasma generator.
1	40. A method of providing ions to an ion implantation system, the
2	method comprising:
3	providing an ion precursor to a transformer-coupled toroidal plasma
4	generator in an ion source;
5	ionizing at least a portion of the ion precursor into ions, the ions having
6	a greater density at a center of the transformer-coupled toroidal plasma generator and
7	extending along a line through the center of the transformer-coupled toroidal plasma
8	generator; and
9	ejecting a portion of the ions out of the ion source.

1	41. A plasma forch head comprising.	
2	an outer nozzle;	
3	an inner nozzle, the inner nozzle including a conduit passing through the	
4	inner nozzle from an inlet side toward an outlet,	
5	a toroidal transformer core surrounding the conduit; and	
6	a bypass providing a return path for a secondary plasma current circuit	
7	around the toroidal transformer core.	
	42. The plasma torch head of claim 41 wherein the inner nozzle	
1	42. The plasma torch head of claim 41 wherein the finder nozzle comprises metal and further including a dielectric spacer in the inner nozzle to prevent	
2	an electric path through the inner nozzle around the toroidal transformer core.	
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1	43. The plasma torch head of claim 41 wherein a first gas is flown	
2	through the conduit and a second gas if flown through the bypass, the first gas being	
3	different from the second gas.	
	44. The plasma torch head of claim 43 wherein the first gas is	
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2	oxygen and the second gas is either propane or hydrogen.	
1	45. The plasma torch head of claim 41 further comprising a primary	r
2	coil disposed to couple electro-magnetic energy to the toroidal transformer core	
3	wherein the primary coil and the toroidal transformer core are enclosed within the inne	er
4	noggle	
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1	46. A method of cutting material using a plasma torch, the method	
2	comprising:	
3	flowing a plasma precursor in a conduit through a center of a toroidal	
4	transformer core of a plasma generator in an inner nozzle of a plasma torch;	
5	forming plasma from the plasma precursor;	
. 6	completing a plasma current secondary circuit around the toroidal	
7	transformer core through a bypass; and	
8	transporting plasma out an outlet of the plasma torch.	
1	47. The method of claim 46 further comprising flowing carrier gas	;
2	through the bypass.	

1	48. The method of claim 46 wherein the forming plasma step
2	includes providing a primary voltage to a primary coil coupling electro-magnetic
3	energy to the toroidal transformer core, the primary voltage being an alternating-current
4	voltage less than about 115 Volts.
1	49. An ion source for an ion milling apparatus, the ion source
2	comprising:
3	a transformer-coupled toroidal plasma generator (having a primary coil
4	disposed to couple electro-magnetic energy to a toroidal core, the transformer-coupled
5	toroidal plasma generator disposed to provide plasma along a center line of the
6	transformer-coupled toroidal plasma generator toward an accelerator plate.
1	50. The ion source of claim 1 wherein the transformer-coupled
2	toroidal plasma generator further includes a second toroidal core.
1	51. A method for providing ions to an ion milling apparatus, the
2	method comprising:
3	providing an ion precursor to a transformer-coupled toroidal plasma
4	generator;
5	ionizing at least a portion of the ion precursor to form ions, the ions
6	being concentrated along a center axis of the transformer-coupled toroidal plasma
7	generator; and
8	ejection a portion of the ions toward an accelerator plate.
1	52. The method of claim 51 wherein the ion precursor forms reactive
2	ions.